







SN74LV4T125 SCLS749C - FEBRUARY 2014 - REVISED JUNE 2022

SN74LV4T125 Single Power Supply Quadruple Buffer Translator GATE With 3-State **Output CMOS Logic Level Shifter**

1 Features

- Single-Supply Voltage Translator at 5.0-V, 3.3-V, 2.5-V, and 1.8-V V_{CC}
- Operating Range of 1.8 V to 5.5 V
- Up Translation
 - 1.2 V⁽¹⁾ to 1.8 V at 1.8-V V_{CC}
 - 1.5 V⁽¹⁾ to 2.5 V at 2.5-V V_{CC}
 - 1.8 V⁽¹⁾ to 3.3 V at 3.3-V V_{CC}
 - 3.3 V to 5.0 V at 5.0-V V_{CC}
- **Down Translation**
 - 3.3 V to 1.8 V at 1.8-V V_{CC}
 - 3.3 V to 2.5 V at 2.5-V V_{CC}
 - 5.0 V to 3.3 V at 3.3-V V_{CC}
- Logic Output is Referenced to V_{CC}
- Characterized up to 50 MHz at 3.3-V V_{CC}
- 5.5 V Tolerance on Input Pins
- -40°C to 125°C Operating Temperature Range
- Pb-Free Packages Available: SC-70 (RGY) - 3.5 × 3.5 × 1 mm
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Supports Standard Logic Pinouts
- Ioff Support Partial-Power-Down Mode Operation
- CMOS Output B Compatible with AUP125, LVC125¹

2 Applications

- Tablet
- Smartphone
- Personal Computer
- Industrial Automotive

3 Description

SN74LV4T125 is a low-voltage CMOS buffer gate that operates at a wider voltage range for portable, telecom, industrial, and automotive applications. The output level is referenced to the supply voltage and is able to support 1.8-V, 2.5-V, 3.3-V, and 5-V CMOS levels.

The input is designed with a lower threshold circuit to match 1.8-V input logic at V_{CC} = 3.3 V and can be used in 1.8 V to 3.3 V level-up translation. In addition, the 5-V tolerant input pins enable down translation (for example, 3.3 V to 2.5 V output at V_{CC} = 2.5 V). The wide V_{CC} range of 1.8 V to 5.5 V allows the generation of desired output levels to connect to controllers or processors.

The SN74LV4T125 device is designed with currentdrive capability of 8 mA to reduce line reflections, overshoot, and undershoot caused by high-drive outputs.

Device Information

| PART NUMBER ⁽¹⁾ | PACKAGE | BODY SIZE (NOM) | | |
|----------------------------|----------------|-------------------|--|--|
| SN74LV4T125 | PW (TSSOP, 14) | 5.00 mm x 4.40 mm | | |
| 311742041123 | RGY (VQFN, 14) | 3.50 mm x 3.50 mm | | |

For all available packages, see the orderable addendum at (1)the end of the data sheet.

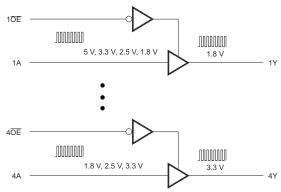


Figure 3-1. Simplified Application Diagram

¹ Refer the V_{IH}/V_{IL} and output drive for lower V_{CC} condition.

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

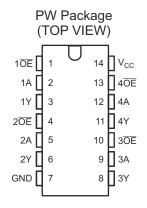
| C | hanges from Revision B (March 2014) to Revision C (June 2022) | Page |
|---|--|--------|
| • | I _{off} Support Partial-Power-Down Mode Operation to Features | 1 |
| • | Updated the numbering format for tables, figures, and cross-references throughout the document | 1 |
| • | Added ESD Ratings table, Receiving Notification of Documentation Updates section, and Support Reso | ources |
| | section | 1 |
| | | |

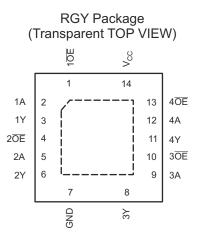
| • | Updated Features. | |
|--------|---|-------|
| | Updated Pin Functions table. | |
| | Added ESD Ratings table, Thermal Information table, Typical Characteristics section, Pin Configuratio | |
| | Functions section, Detailed Description section, Power Supply Recommendations section, Layout sec | tion, |
| | Receiving Notification of Documentation Updates section, and Community Resources section | 4 |
| • | Updated Detailed Design Procedure section. | 13 |
| - c | hanges from Revision * (February 2014) to Revision A (March 2014) | Pag |

| _ | | | | , | , | |
|---|----------------|---------------|------------|-------------|------|---|
| • | Updated 1 page | preview docur | nent to fu | ull version | | 1 |



5 Pin Configuration and Functions





Pin Functions

| Р | IN | TYPE (1) | DESCRIPTION |
|-----|-----------------|-----------------|-------------|
| NO. | NAME | | DESCRIPTION |
| 1 | 1 OE | I | Enable 1 |
| 2 | 1A | I | Input 1 |
| 3 | 1Y | 0 | Output 1 |
| 4 | 2 OE | I | Enable 2 |
| 5 | 2A | I | Input 2 |
| 6 | 2Y | 0 | Output 2 |
| 7 | GND | _ | Ground Pin |
| 8 | 3Y | 0 | Output 3 |
| 9 | 3A | I | Input 3 |
| 10 | 3 OE | I | Enable 3 |
| 11 | 4Y | 0 | Output 4 |
| 12 | 4A | I | Input 4 |
| 13 | 4 OE | | Enable 4 |
| 14 | V _{CC} | | Power Pin |

(1) I = Input, O = Output, I/O = Input or Output, G = Ground, P = Power.



6 Specifications 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | | MIN | MAX | UNIT |
|------------------|------------------------------------|---|------|-----------------------|------|
| V _{CC} | Supply voltage range | | -0.5 | 7.0 | V |
| VI | Input voltage range ⁽²⁾ | | -0.5 | 7.0 | V |
| V | Voltage range applied to a | ny output in the high-impedance or power-off state ⁽²⁾ | -0.5 | 4.6 | V |
| Vo | Voltage range applied to a | ny output in the high or low state ⁽²⁾ | -0.5 | V _{CC} + 0.5 | v |
| I _{IK} | Input clamp current | V ₁ < 0 | | -20 | mA |
| I _{OK} | Output clamp current | V_{O} < 0 or V_{O} > V_{CC} | | ±50 | mA |
| lo | Continuous output current | | | ±35 | mA |
| | Continuous current through | n V _{CC} or GND | | ±70 | mA |
| TJ | Junction temperature | | | 150 | °C |
| T _{stg} | Storage temperature | | -65 | 150 | °C |

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| | | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1) | ±2000 | |
| V _(ESD) | Electrostatic discharge | Machine Model (MM), per JEDEC specification | ±200 | v |
| | | Charged-device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾ | ±1000 |] |

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



6.3 Recommended Operating Conditions

| | | | MIN | MAX | UNIT |
|-----------------|------------------------------------|----------------------------------|-----|-----------------|------|
| V _{CC} | Supply voltage | | 1.6 | 5.5 | V |
| VI | Input voltage | | 0 | 5.5 | V |
| Vo | Output voltage | High or Low State | 0 | V _{CC} | V |
| ۷O | Ouput voltage | H-Z | 0 | V _{CC} | V |
| | | V _{CC} = 1.8 V | | -3 | |
| | High lovel output ourrent | V _{CC} = 2.5 V | | -5 | mA |
| I _{OH} | High-level output current | V _{CC} = 3.3 V | | -8 | ma |
| | | V _{CC} = 5.0 V | | -16 | |
| | Low-level output current | V _{CC} = 1.8 V | | 3 | mA |
| | | V _{CC} = 2.5 V | | 5 | |
| I _{OL} | | V _{CC} = 3.3 V | | 8 | |
| | | V _{CC} = 5.0 V | | 16 | |
| | | V _{CC} = 1.6 V to 2.0 V | | 20 | |
| Δt/Δv | Input transition rise or fall rate | V _{CC} = 2.3 V to 2.7 V | | 20 | ns/V |
| | Input transition rise or fall rate | V _{CC} = 3 V or 3.6 V | | 20 | |
| | | V _{CC} = 4.5 V to 5.0 V | | 20 | |
| T _A | Operating free-air temperature | | -40 | 125 | °C |

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

(1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

6.4 Thermal Information

| | | SN74L | V4T125 | |
|---------------------|--|---------|---------|------|
| | THERMAL METRIC ⁽¹⁾ | PW | RGY | UNIT |
| | | 14 PINS | 14 PINS | |
| R _{0JA} | Junction-to-ambient thermal resistance | 126.9 | 52.9 | |
| R _{0JCtop} | Junction-to-case (top) thermal resistance | 54.2 | 67.8 | |
| R _{θJB} | Junction-to-board thermal resistance | 68.6 | 29.0 | °C/W |
| Ψ _{JT} | Junction-to-top characterization parameter | 7.5 | 2.6 | C/VV |
| Ψ _{JB} | Junction-to-board characterization parameter | 68.0 | 29.1 | |
| R _{0JCbot} | Junction-to-case (bottom) thermal resistance | _ | 9.3 | |

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).



6.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

| | PARAMETER | TEST CONDITIONS | V _{cc} | T _A : | = 25°C | T _A = -40°C to | 125°C | UNIT |
|------------------|---|--|--|------------------------------|---------|---------------------------|--------|------|
| | FARAMETER | TEST CONDITIONS | VCC | MIN | TYP MAX | MIN | MAX | UNIT |
| | | | V _{CC} = 1.65 V to 1.9 V | 0.95 | | 1 | | |
| ′ін | High-level input | | V_{CC} = 2.3 V to 2.7 V | 1.1 | | 1.2 | | V |
| ΊΗ | voltage | | V _{CC} = 3 V to 3.6 V | 1.3 | | 1.35 | | v |
| | | | V _{CC} = 4.5 V to 5.0 V | 2 | | 2 | | |
| | Low-level input ^{IL} voltage | | V _{CC} = 1.65 V to 1.9 V | | 0.55 | | 0.5 | |
| , | | | V _{CC} = 2.3 V to 2.77 V | | 0.7 | | 0.6 | |
| ∕ı∟ | | | V _{CC} = 3 V to 3.6 V | | 0.85 | | 0.75 | V |
| | | | V _{CC} = 4.5 V to 5.5 V | | 0.9 | | 0.85 | |
| | | Ι _{ΟΗ} = –50 μΑ | V _{CC} = 1.65 V to 5.5 V | V _{CC} – 0.1 | | V _{CC} - 0.1 | | V |
| | | I _{OH} = –2 mA | V _{CC} = 1.65 V | 1.4 | | 1.35 | | V |
| | | I _{OH} = –3 mA | V _{CC} = 2.3 V | 2.05 | | 2.0 | | V |
| V _{OH} | High-level output | I _{OH} = –5 mA | | 2.7 | | 2.6 | | |
| | voltage | I _{OH} = –8 mA | V _{CC} = 3.0 V | 2.6 | | 2.5 | | V |
| | | I _{OH} = –8 mA | | 3.7 | | 3.6 | | |
| | | I _{OH} = –16 mA | –– V _{CC} = 4.5 V | 3.8 | | 3.7 | | V |
| | | I _{OH} = –16 mA | V _{CC} = 5.0 V | 4.4 | | 4.3 | | V |
| | | I _{OL} = 50 μA | V _{CC} = 1.65 V to 5.5 V | | 0.1 | | 0.1 | V |
| | | | V _{CC} = 1.65 V | | 0.1 | | 0.1 | |
| | | I _{OH} = 2 mA | V _{CC} = 1.8 V | | 0.2 | | 0.3 | V |
| | Low-level output voltage | | V _{CC} = 2.3 V | | 0.2 | | 0.3 | |
| | | I _{OH} = 3 mA | V _{CC} = 2.5 V | | 0.25 | | 0.3 | V |
| V _{OL} | | I _{OH} = 5 mA | | | 0.35 | | 0.4 | V |
| | | I _{OH} = 8 mA | ––– V _{CC} = 3.0 V | | 0.4 | | 0.45 | |
| | | I _{OH} = 8 mA | V _{CC} = 3.3 V | | 0.45 | | 0.5 | V |
| | | I _{OH} = 8 mA | | | 0.50 | | 0.55 | |
| | | I _{OH} = 16 mA | $V_{CC} = 4.5 V$ | V _{CC} = 4.5 V 0.55 | | 0.55 | V | |
| | | I _{OH} = 16 mA | V _{CC} = 5.0 V | | 0.55 | | 0.55 | V |
| I | Input leakage current | V _I =0 V or V _{CC} | V _{CC} = 0 V, 1.8 V, 2.5 V, 3.3 V, 5.5 V | | ±0.1 | | ±1 | μA |
| | | | V _{CC} = 5.0 V | | 2 | | 20 | |
| | Static supply | $V_1 = 0 V \text{ or } V_{CC}$ | V _{CC} = 3.3 V | | 2 | | 20 | |
| lcc | current | $I_0 = 0$; open on loading | V _{CC} = 2.5 V | | 2 | | 20 | μA |
| | | | V _{CC} = 1.8 V | | 2 | | 20 | |
| AL | Additional static | One input at 0.3 V or 3.4 V Other inputs at 0 or V _{CC} , $I_0 = 0$ | V _{CC} = 5.5 V | | 1.35 | | 1.5 | |
| ∆l _{CC} | supply current | One input at 0.3 V or 1.1 V Other inputs at 0 or V _{CC} , $I_0 = 0$ | V _{CC} = 1.8 V | | 1.00 | | 1.5 µ/ | μΑ |
| oz | Off-state (High Impedance State) Output Current | V _O = V _{CC} or GND | V _{CC} = 5.5 V | | ±0.25 | | ±2.5 | μA |
| off | Partial power down current | V_{O} or V_{I} = 0 to 5.5 V | V _{CC} = 0 V | | 0.5 | | 5 | μA |
| Ci | Input capacitance | V _I = V _{CC} or GND | V _{CC} = 3.3 V | | 1.6 | 1.6 | | pF |
| Co | Output capacitance | V _O = V _{CC} or GND | V _{CC} = 3.3 V | | 4.8 | 4.8 | | pF |



6.6 Switching Characteristics

| PARAMETER | FROM | то | FREQUENCY | | | ٦ | Γ _A = 25°C | | T _A = - | 65°C to 12 | 5°C | | | |
|--|--|----------|---|---|-------|-------|-----------------------|------|--|---|------|------|---|--|
| PARAMETER | (INPUT) | (OUTPUT) | (TYP) | Vcc | CL | MIN | TYP | MAX | MIN | TYP | MAX | UNIT | | |
| | | | | 5.0.1/ | 15 pF | | 2.8 | 3.2 | | 3 | 3.5 | | | |
| pd | | | DC to 50 MHz | 5.0 V | 30 pF | | 3 | 3.5 | | 3 | 4.5 | | | |
| | | | | 221 | 15 pF | | 4 | 4.5 | | 5 | 5.5 | ns | | |
| | Anyln | Y | | 3.3 V | 30 pF | | 5 | 5.5 | | 5.5 | 6.5 | | | |
| t _{pd} Any I | Any in | Ť | DC to 50 MHz | 251 | 15 pF | | 5.5 | 6.5 | | 7 | 7.5 | 20 | | |
| | | | DC to 50 MIHZ | 2.5 V | 30 pF | | 6.5 | 7 | | 7.5 | 8.5 | ns | | |
| | | | | 1.9.1/ | 15 pF | | 10 | 11 | | 11 | 12 | 20 | | |
| | | | $ \begin{array}{ c c c c c c c } \hline DC \mbox{ to } 30 \mbox{ MHz} & 1.8 \mbox{ V} & \hline & 30 \mbox{ pF} & 11 & 12 \\ \hline & & & & & & & & & & & & & & & & & &$ | | 12.5 | 13 | ns | | | | | | | |
| | | | | 5.0.1/ | 15 pF | | 3.5 | 4 | | 3.5 | 4 | | | |
| | | | | 5.0 V | 30 pF | | 3.8 | 4.2 | | 4 | 4.5 | | | |
| | | | DC to 50 MHZ | 2.2.1 | 15 pF | | 5 | 5.8 | | 5.8 | 6.1 | ns | | |
| | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | | 5.5 | 6 | | 5.7 | 6.5 | | | | | | | |
| t _{PZH} | UE | Y | | V _{CC} CL MIN TYP MAX MIN TYP MAX 42 $5.0 \vee$ $15 pF$ 2.8 3.2 3 3 $3.3 \vee$ $15 pF$ 2.8 3.2 3 5 3 3 3 5 3 3 5 6 5 7 7 5 8 8 5 9 1 1 1 1 1 1 5 1 1 | 9 | | | | | | | | | |
| | | | | 2.5 V | 30 pF | | 8 | 8.5 | | 9 | 9.5 | ns | | |
| | | | | 101/ | 15 pF | | 14.5 | 15 | | 15.5 | 16.5 | | | |
| | | | DC to 30 MHz | 1.8 V | 30 pF | | 15.5 | 16 | 3.2 3 3.5 3 4.5 5 5.5 5.5 6.5 7 7 7.5 11 11 12 12.5 4 3.5 4.2 4 5.8 5.8 6 5.7 8 8.5 8.5 9 15 15.5 16 16 3.5 3.5 4 4 5.6 6 6.2 7 8.5 9 9.5 10.5 7.5 18 8.5 19 3.5 3.5 4 4 4 4.5 6 6.5 6 6 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 8 | 17 | ns | | | |
| t _{PZL} | | | | | | 5.0.1 | 15 pF | | 3 | 3.5 | | 3.5 | 4 | |
| | | | DC to 50 MHz | 5.0 V | 30 pF | | 3.5 | 4 | | 4 | 4.5 | ns | | |
| | | | | | 15 pF | | 5.3 | 5.6 | | 6 | 6.2 | | | |
| | | | | 3.3 V | 30 pF | | 5.8 | 6.2 | | 7 | 7.5 | | | |
| | OE | Y | | | 15 pF | | 8 | 8.5 | | 9 | 9.5 | | | |
| | | | | 2.5 V | 30 pF | | 9 | 9.5 | | 10.5 | 11 | ns | | |
| | | | | 4.011 | | | 17 | 17.5 | | 18 | 18.5 | ns | | |
| | | | DC to 30 MHz | 1.8 V | | | 18 | 18.5 | | 19 | 20 | | | |
| | | | | Hz | | | 3 | | | 3.5 | 4 | | | |
| | | | | | | | 3.5 | 4 | | 4 | 4.5 | ns | | |
| | | | DC to 50 MHz | | | | 3.5 | 4 | | 4.5 | 5 | | | |
| | | | | 3.3 V | 30 pF | | 5 | 6 | | 6.5 | 7 | | | |
| t _{PHZ} | OE | Y | | | | | 5.5 | 6 | | 6 | 6.5 | | | |
| | $ \begin{array}{c c c c c c c } & & & & & & & & & & & & & & & & & & &$ | 7.5 | 8 | | 8 | 9 | ns | | | | | | | |
| DC to 30 MHz 1.8 V 30 pF 30 pF 30 pF 30 pF 30 pF 30 pF 30 pF DC to 50 MHz 5.0 V 15 pF 30 pF 30 pF 15 pF 30 pF DC to 50 MHz 2.5 V 15 pF 30 pF DC to 30 MHz 1.8 V 15 pF 30 pF 30 pF 15 pF 30 pF 30 pF DC to 50 MHz 2.5 V 15 pF 30 pF 30 pF 30 pF DC to 30 MHz 1.8 V 15 pF 30 pF 30 pF 30 pF 30 pF 30 pF 30 pF 30 pF 30 p | | | | | | 8.5 | | | | | | | | |
| | | | DC to 30 MHz | 1.8 V | | | | | | | 13 | ns | | |
| | | | | | | | 2 | 2.5 | | 2 | 2.7 | | | |
| | | | | 5.0 V | | | 2 | 3 | | 2 | 3.2 | | | |
| | | | DC to 50 MHz | | | | 2.3 | 2.8 | | 2.5 | 3.2 | ns | | |
| | | | | 3.3 V | 30 pF | | 2.8 | 3.2 | | | 4 | | | |
| t _{PLZ} | OE | Y | | | | | 3.3 | 3.8 | | 3.8 | 4.2 | | | |
| | | | DC to 50 MHz | 2.5 V | | | | | | | 5 | ns | | |
| | | | | | | | | | | | 5.7 | | | |
| | | | DC to 30 MHz | 1.8 V | | | | | | | 8.5 | ns | | |
| | | | DC to 50 MHz | to | 15 pF | | | | | | | | | |
| $\overline{DC} = \left(\begin{array}{c c} & & & & & & & & & & & & & & & & & & &$ | | 1 | | 1 | ns | | | | | | | | | |
| | | | DC to 30 MHz | 1.8 V | 15 pF | | | | | 9 9.5 10.5 11 18 18.5 19 20 3.5 4 4 4.5 4.5 5 6.5 7 6 6.5 12 13 2 2.7 2 3.2 3.3 4 3.8 4.2 5 5.7 7 8.5 | | | | |

over operating free-air temperature range (unless otherwise noted) (see Figure 7-1)



6.7 Noise Characteristics

 V_{CC} = 3.3 V, C_{L} = 50 pF, T_{A} = 25°C⁽¹⁾

| | PARAMETER | MIN | TYP | MAX | UNIT |
|--------------------|---|------|------|------|------|
| V _{OL(P)} | Quiet output, maximum dynamic V _{OL} | | 0.4 | 0.8 | V |
| V _{OL(V)} | Quiet output, minimum dynamic V _{OL} | | -0.3 | -0.8 | V |
| V _{OH(V)} | Quiet output, minimum dynamic V _{OH} | | 3 | | V |
| V _{IH(D)} | High-level dynamic input voltage | 2.31 | | | V |
| V _{IL(D)} | Low-level dynamic input voltage | | | 0.99 | V |

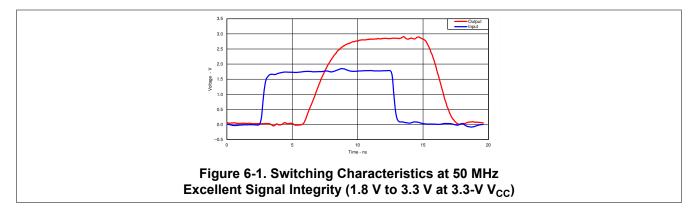
(1) Characteristics are for surface-mount packages only.

6.8 Operating Characteristics

V_{CC} = 5 V, T_A = 25°C

| | PARAMETER | TEST CONDITIONS | TYP | UNIT |
|-----------------|-------------------------------|------------------------------------|-----|------|
| C _{pd} | Power dissipation capacitance | C _L = 50 pF, f = 10 MHz | 16 | pF |

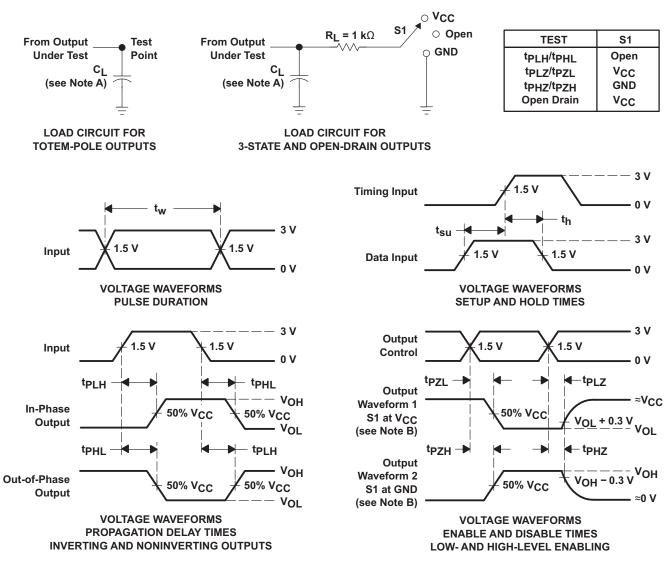
6.9 Typical Characteristics





7 Parameter Measurement Information

7.1



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r \leq 3 ns, t_f \leq 3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.



8 Detailed Description

8.1 Overview

The SN74LVxTxx family was created to allow up- or down-voltage translation with only one power rail. The family has over-voltage tolerant inputs that allow down translation from up to 5.5 V to the V_{CC} level that can be as low as 1.8 V. The family SN74LVxTxx also has a lowered switching threshold that allows it to translate up to the V_{CC} level that can be as high as 5.5 V.

8.1.1 Translating Down

Using these parts to translate down is very simple. Because the inputs are tolerant to 5.5 V at any valid V_{CC} , they can be used to down translate. The input can be any level above V_{CC} up to 5.5 V and the output will equal the V_{CC} level, which can be as low as 1.8 V. One important advantage to down translating using this part is that the I_{CC} current will remain less than or equal to the specified value.

Down translation possibilities with SN74LVxTxx:

- With 1.8-V V_{CC} from 2.5 V, 3.3 V, or 5 V down to 1.8 V.
- With 2.5-V V_{CC} from 3.3 V or 5 V down to 2.5 V.
- With 3.3-V V_{CC} from 5 V down to 3.3 V.

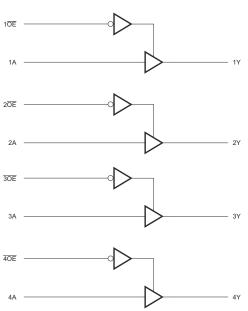
8.1.2 Translating Up

Using the SN74LVxTxx family to translate up is very simple. The input switching threshold is lowered so the high level of the input voltage can be much lower than a typical CMOS V_{IH}. For instance, If the V_{CC} is 3.3 V then the typical CMOS switching threshold would be V_{CC} / 2 or 1.65 V. This means the input high level must be at least V_{CC} × 0.7 or 2.31 V. On the LVxT devices the input threshold for 3.3-V V_{CC} is approximately 1 V. This allows a signal with a 1.8-V V_{IH} to be translated up to the V_{CC} level of 3.3 V.

Up translation possibilities with SN74LVxTxx:

- With 2.5-V V_{CC} from 1.8 V to 2.5 V.
- With 3.3-V V_{CC} from 1.8 V or 2.5 V to 3.3 V.
- With 5-V V_{CC} From 2.5 V or 3.3 V to 5 V.

8.2 Functional Block Diagram



8.3 Feature Description

This part is a single supply buffer that is capable up or down translation. The output will equal V_{CC} while the input can vary from 1.2 V to 5.5 V.



Up Translation Mode:

- 1.2 V to 1.8 V at 1.8-V V_{CC}
- 1.5 V to 2.5 V at 2.5-V V_{CC}
- 1.8 V to 3.3 V at 3.3-V V_{CC}
- 3.3 V to 5.0 V at 5.0-V V_{CC}

Down Translation Mode:

- 3.3 V to 1.8 V at 1.8-V V_{CC}
- 3.3 V to 2.5 V at 2.5-V V_{CC}
- 5.0 V to 3.3 V at 3.3-V V_{CC}

8.4 Device Functional Modes

This device performs the function of a buffer where input logic level equals the output logic level, while providing buffering and drive to the output. The SN74LV4T125 device will also translate voltages up or down while performing this function.

Table 8-1. Function Table (Each Buffer)

| INPUT | OUTPUT ⁽²⁾ | |
|-------|-----------------------|---|
| ŌĒ | Α | Y |
| L | Н | Н |
| L | L | L |
| Н | Х | Z |

Table 8-2. Supply V_{CC} = 3.3 V

| INPI (Lower Le | JT b evel Input) | OUTPUT (V _{CC} CMOS) |
|-----------------------|---------------------|----------------------------------|
| А | В | Y |
| V _{IH} (min) | = 1.35 V | V _{OH} (min) = 2.9 V |
| V _{IL} (max |) = 0.8 V | V _{OL} (max) = 0.2 V |

 H = High Voltage Level, L = Low Voltage Level, X = Do not Care, Z = High Impedance

(2) H = Driving High, L = Driving Low, Z = High Impedance State



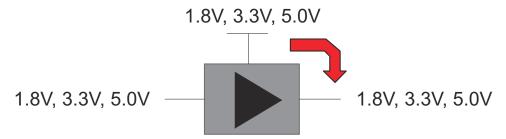
9 Applications and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

Based upon the lower-threshold circuit design of the LVxT family, the LVxT family also supports level translation. For level translation up and down, the LVxT family requires only a single power supply.



Standard Logic Mode 1.8V, 3.3V

9.2 Typical Application VIH = 2.0V VIL = 0.8V VIH = 0.99V VIL = 0.55V Vcc = 5.0V Vcc = 1.8V 5.0V, 3.3V 2.5V, 1.8V 1.5V, 1.2V System 5.0V 3.3V System 5.0V System 1.8V LV1Txx Logic LV1Txx Logic System Vcc = 3.3V 5.0V, 3.3V LV1Txx Logic 3.3V 2.5V, 1.8V System System VOH min = 2.4VVIH min = 1.36\ VOL max = 0.4V VIL min = 0.8V Figure 9-1. Switching Thresholds for 1.8 V to 3.3 V Translation



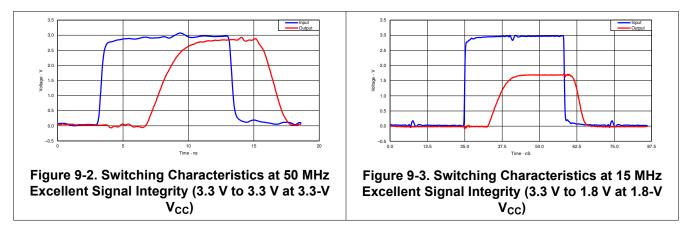
9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. The input threshold levels are lowered to allow for up translation. At 5 V the device has equivalent TTL input levels.

9.2.2 Detailed Design Procedure

- 1. Recommended input conditions:
 - Rise time and fall time specifications. See ($\Delta t/\Delta V$) in *Recommended Operating Conditions* table.
 - Specified high and low levels. See (V_{IH} and V_{IL}) in *Recommended Operating Conditions* table.
 - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC} .
- 2. Recommend output conditions:
 - Load currents should not exceed 35 mA per output and 70 mA total for the part.
 - Outputs should not be pulled above V_{CC}.

9.2.3 Application Curves



10 Power Supply Recommendations

The power supply can be any voltage between the Min and Max supply voltage rating located in the *Recommended Operating Conditions*.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μ F is recommended. If there are multiple V_{CC} pins, then 0.01 μ F or 0.022 μ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 μ F and 1 μ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.



11 Layout 11.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in Figure 11-1 are the rules that must be observed under all circumstances.

All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} whichever make more sense or is more convenient.

It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin it will disable the outputs section of the part when asserted. This will not disable the input section of the IOs so they also cannot float when disabled.

11.2 Layout Example



Figure 11-1. Layout Diagram



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Additional Product Selection

| DEVICE | PACKAGE | DESCRIPTION |
|-------------|---------------|--|
| SN74LV1T00 | DCK, DBV | 2-Input Positive-NAND Gate |
| SN74LV1T02 | DCK, DBV | 2-Input Positive-NOR Gate |
| SN74LV1T04 | DCK, DBV | Inverter Gate |
| SN74LV1T08 | DCK, DBV | 2-Input Positive-AND Gate |
| SN74LV1T34 | DCK, DBV, DRL | Single Buffer Gate |
| SN74LV1T14 | DCK, DBV | Single Schmitt-Trigger Inverter Gate |
| SN74LV1T32 | DCK, DBV | 2-Input Positive-OR Gate |
| SN74LV1T86 | DCK, DBV | Single 2-Input Exclusive-Or Gate |
| SN74LV1T125 | DCK, DBV, DRL | Single Buffer Gate with 3-state Output |
| SN74LV1T126 | DCK, DBV, DRL | Single Buffer Gate with 3-state Output |
| SN74LV4T125 | RGY, PW | Quadruple Bus Buffer Gate With 3-State Outputs |

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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12.4 Trademarks

TI E2E[™] is a trademark of Texas Instruments.

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12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| SN74LV4T125PWR | ACTIVE | TSSOP | PW | 14 | 2000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 125 | LV4T125 | Samples |
| SN74LV4T125RGYR | ACTIVE | VQFN | RGY | 14 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | LVT125 | Samples |

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74LV4T125 :

• Automotive : SN74LV4T125-Q1

• Enhanced Product : SN74LV4T125-EP

NOTE: Qualified Version Definitions:

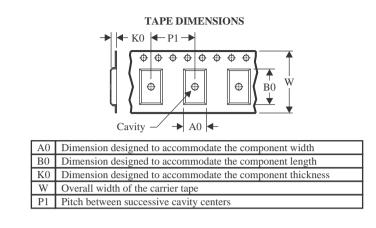
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications



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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| *All dimensions are nominal | | | | | | | | | | | | |
|-----------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
| SN74LV4T125PWR | TSSOP | PW | 14 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| SN74LV4T125RGYR | VQFN | RGY | 14 | 3000 | 330.0 | 12.4 | 3.75 | 3.75 | 1.15 | 8.0 | 12.0 | Q1 |



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PACKAGE MATERIALS INFORMATION

12-Jun-2024



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74LV4T125PWR | TSSOP | PW | 14 | 2000 | 353.0 | 353.0 | 32.0 |
| SN74LV4T125RGYR | VQFN | RGY | 14 | 3000 | 360.0 | 360.0 | 36.0 |

MECHANICAL DATA



- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- earrow Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated.
- The Pin 1 identifiers are either a molded, marked, or metal feature.
- G. Package complies to JEDEC MO-241 variation BA.



PW0014A



PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



PW0014A

EXAMPLE BOARD LAYOUT

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PW0014A

EXAMPLE STENCIL DESIGN

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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